



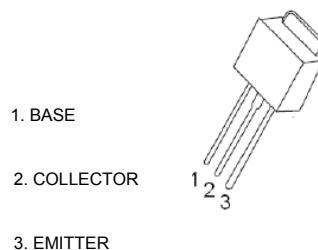
## TO-251-3L Plastic-Encapsulate Transistors

### 2SB1261-Z TRANSISTOR (PNP)

#### FEATURES

- High  $h_{FE}$
- Low  $V_{CE(sat)}$

#### TO-251-3L



#### MAXIMUM RATINGS ( $T_a=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Value	Unit
$V_{CBO}$	Collector-Base Voltage	-60	V
$V_{CEO}$	Collector-Emitter Voltage	-60	V
$V_{EBO}$	Emitter-Base Voltage	-7	V
$I_C$	Collector Current -Continuous	-3	A
$P_D$	Collector Power Dissipation	1	W
$T_J$	Junction Temperature	150	$^\circ C$
$T_{stg}$	Storage Temperature	-55-150	$^\circ C$

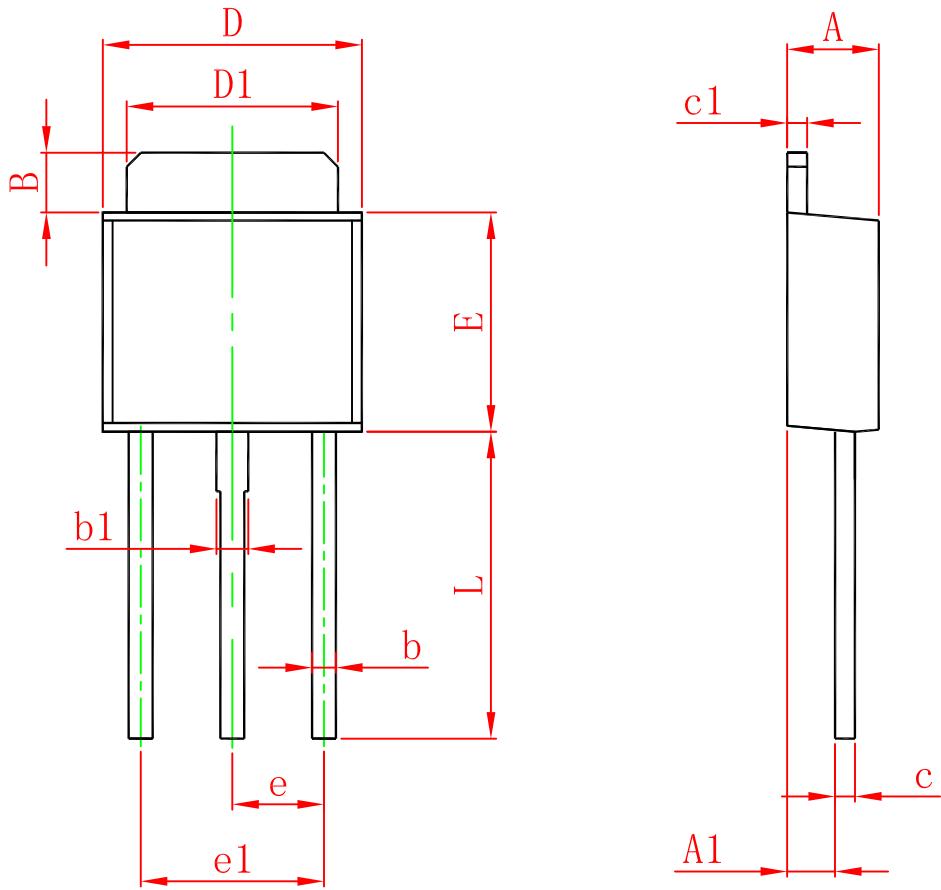
#### ELECTRICAL CHARACTERISTICS ( $T_a=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-100\mu A, I_E=0$	-60			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -1mA, I_B=0$	-60			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-100\mu A, I_C=0$	-7			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=-60V, I_E=0$			-10	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=-7V, I_C=0$			-10	$\mu A$
DC current gain	$h_{FE(1)}$	$V_{CE}=-2V, I_C=-200mA$	60			
	$h_{FE(2)}$	$V_{CE}=-2V, I_C=-600mA$	100		400	
	$h_{FE(3)}$	$V_{CE}=-2V, I_C=-2A$	50			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=-1.5A, I_B=-150mA$			-0.3	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=-1.5A, I_B=-150mA$			-1.2	V
Transition frequency	$f_T$	$V_{CE}=-5V, I_C=-1.5A$	50			MHz
Collector output capacitance	$C_{ob}$	$V_{CB}=-10V, I_E=0, f=1MHz$	40			pF
Switching Time	Turn on Time	$t_{on}$		0.5		$\mu s$
	Storage Time	$t_{stg}$	$V_{CC}=-10V, I_C=-1A, I_{B1}=-I_{B2}=-0.1A, R_L=10\Omega$	2.0		
	Fall Time	$t_f$		0.5		

#### CLASSIFICATION OF $h_{FE(2)}$

Rank	M	L	K
Range	100-200	160-320	200-400

## TO-251-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.400	0.087	0.094
A1	1.050	1.350	0.042	0.054
B	1.350	1.650	0.053	0.065
b	0.500	0.700	0.020	0.028
b1	0.700	0.900	0.028	0.035
c	0.430	0.580	0.017	0.023
c1	0.430	0.580	0.017	0.023
D	6.350	6.650	0.250	0.262
D1	5.200	5.400	0.205	0.213
E	5.400	5.700	0.213	0.224
e	2.300 TYP.		0.091 TYP.	
e1	4.500	4.700	0.177	0.185
L	7.500	7.900	0.295	0.311

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